



DMT10H015LFG

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	Ι <sub>D</sub> T <sub>C</sub> = +25°C
	13.5mΩ @ V <sub>GS</sub> = 10V	42A
100V	18mΩ @ V <sub>GS</sub> = 6.0V	36A
	23.5mΩ @ V <sub>GS</sub> = 4.5V	32A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Synchronous Rectifier
- Backlighting
- Power Management Functions
- DC-DC Converters

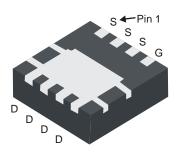
#### **100V N-CHANNEL ENHANCEMENT MODE MOSFET**

### **Features and Benefits**

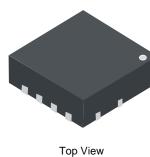
- Low R<sub>DS(ON)</sub> Ensures On State Losses Are Minimized
- Excellent Q<sub>gd x</sub> R<sub>DS (ON)</sub> Product (FOM)
- Advanced Technology for DC/DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of The Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% UIS (Avalanche) Rated
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

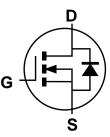
#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (Approximate)



Bottom View





Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMT10H015LFG-7	PowerDI3333-8	2,000/Tape & Reel
DMT10H015LFG-13	PowerDI3333-8	3,000/Tape & Reel

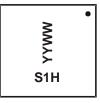
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



S1H = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

DMT10H015LFG Document number: DS38222 Rev. 4 - 2

Notes:



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	100	V		
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	10 8.0	A	
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	42 26	А	
Maximum Continuous Body Diode Forward Current (Note 5)		Is	1.5	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	75	А	
Avalanche Current (L = 3mH)		las	7.5	A	
Avalanche Energy (L = 3mH)		E <sub>AS</sub>	85	mJ	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.0	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>0JA</sub>	61	°C/W
Total Power Dissipation	T <sub>C</sub> = +25°C	PD	35	W
Thermal Resistance, Junction to Case		$R_{ ext{ heta}JC}$	3.5	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

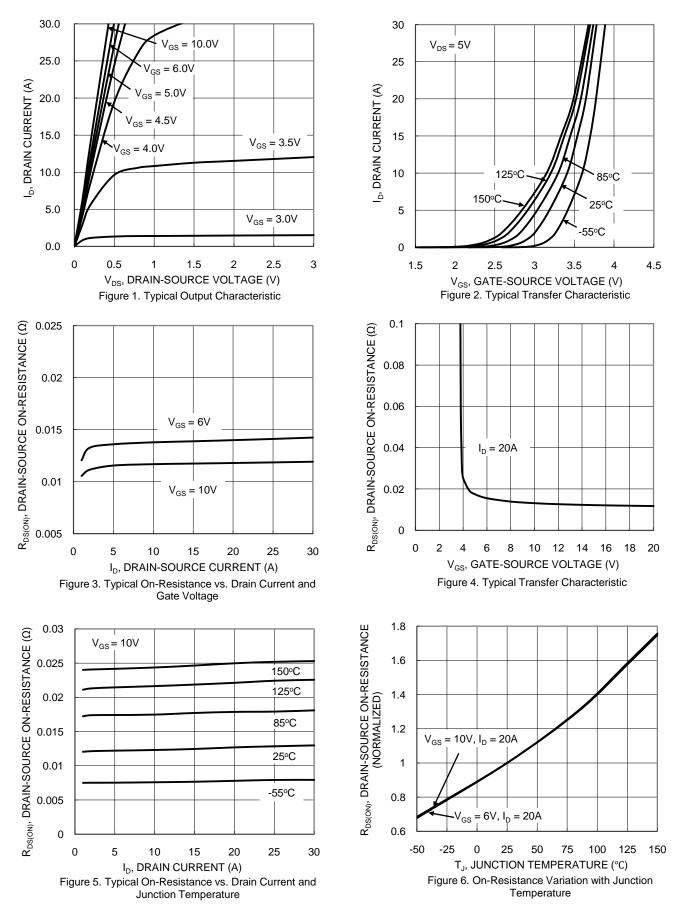
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	—	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.4	2.0	3.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		—	10.8	13.5		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	13.3	18	mΩ	$V_{GS} = 6.0V, I_D = 20A$	
		_	17.9	23.5		$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 7)	-	-	-	-			
Input Capacitance	Ciss	_	1,871	—		$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	—	261	—	pF		
Reverse Transfer Capacitance	Crss	—	6.9	_			
Gate Resistance	R <sub>G</sub>	—	0.75	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	33.3	_		$V_{DD} = 50V, I_D = 10A,$ $V_{GS} = 10V$	
Gate-Source Charge	Q <sub>gs</sub>	—	6.9	_	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	5.1	_		VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	7.0	_		$V_{DD} = 50V, V_{GS} = 10V, \label{eq:VDD} I_D = 10A, R_G = 6\Omega$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	19.7	_	ns		
Turn-Off Fall Time	tF	—	8.1	—	]		
Reverse Recovery Time	t <sub>RR</sub>		37.9	_	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	51.9	_	nC	I <sub>F</sub> = 10A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



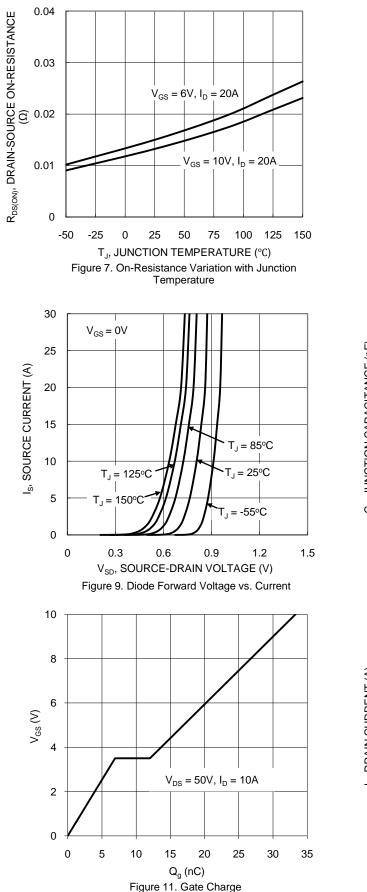
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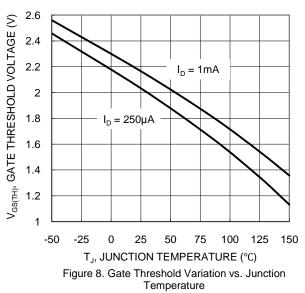


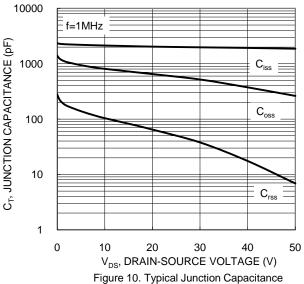
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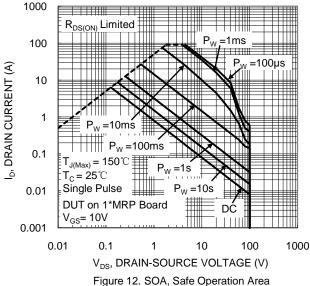


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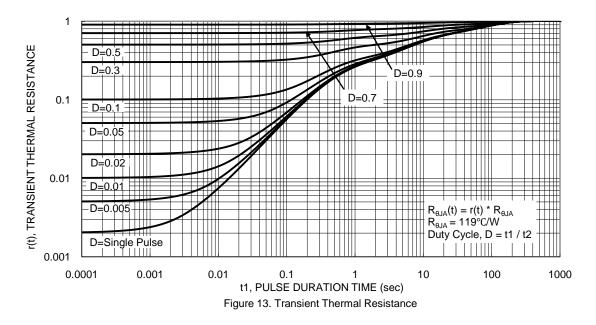






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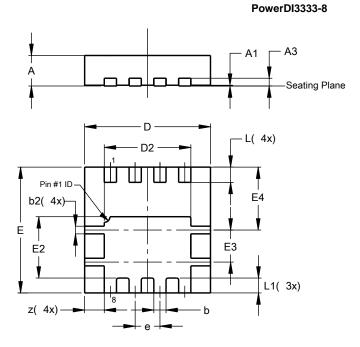






## **Package Outline Dimensions**

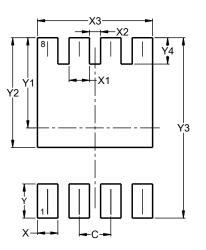
Please see http://www.diodes.com/package-outlines.html for the latest version.



	PowerDI3333-8					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	_	-	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
z	_	-	0.515			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions Value (in mm) С 0.650 0.420 Х X1 0.420 Х2 0.230 Х3 2.370 Y 0.700 Y1 1.850 Y2 2.250 Y3 3.700 Y4 0.540

#### PowerDI3333-8



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